

The Infinite Bandwidth Company™

General Description

The MIC7111 is a micropower operational amplifier featuring rail-to-rail input and output performance in Micrel's IttyBitty[™] SOT-23-5 package. The MIC7111 is ideal for systems where small size is a critical consideration.

The MIC7111 is designed to operate from 1.8V to 11V power supplies.

The MIC7111 benefits small battery operated portable electronic devices where small size and the ability to place the amplifier close to the signal source are primary design concerns.

For other package options, please contact the factory.

MIC7111

1.8V IttyBitty™ Rail-to-Rail Input/Output Op Amp

Final Information

Features

- Small footprint SOT-23-5 package
- Guaranteed performance at 1.8V, 2.7V, 5V, and 10V
- 15μA typical supply current at 1.8V
- · 25kHz gain-bandwidth at 5V
- Output swing to within 1mV of rails with 1.8V supply and 100kΩ load
- Suitable for driving capacitive loads

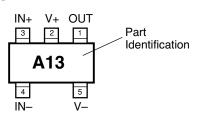
Applications

- · Wireless and cellular communications
- · GaAs RF amplifier bias amplifier
- · Current sensing for battery chargers
- Reference voltage buffer
- Transducer linearization and interface
- Portable computing

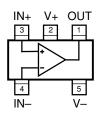
Ordering Information

Part Number			
Standard	Pb-free	Junction Temp. Range	Package
MIC7111BM5	MIC7111YM5	–40°C to +85°C	SOT-23-5

Pin Configuration



Functional Configuration



SOT-23-5 (M5)

Pin Description

Pin Number	Pin Name	Pin Function
1	OUT	Amplifier Output
2	V+	Positive Supply
3	IN+	Noninverting Input
4	IN–	Inverting Input
5	V-	Negative Suppy

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Supply Voltage $(V_{V+} - V_{V-})$
Differential Input Voltage $(V_{IN+} - V_{IN-}) \dots \pm (V_{V+} - V_{V-})$
I/O Pin Voltage (V _{IN} , V _{OUT}), Note 2
$V_{V+} + 0.3V$ to $V_{V-} - 0.3V$
Junction Temperature (T _J)+150°C
Storage Temperature65°C to +150°C
Lead Temperature (soldering, 10 sec.) 260°C
ESD, Note 5 2kV

Operating Ratings (Note 1)

Max. Power Dissipation Note 3
Package Thermal Resistance (θ_{JA}) , Note 4
Max. Junction Temperature (T _{J(max)}), Note 3 +85°C
Junction Temperature (T_J) 40°C to +85°C
Supply Voltage $(V_{V+} - V_{V-})$ 1.8V to 11V

DC Electrical Characteristics (1.8V)

$V = \pm 1.8 V V = 0 V V$	-V $-V$ $/2$ B $-1M$ T	$_{\rm J}$ = 25°C, bold values indicate –40°C \leq T	< +85°C: unless noted
$v_{V_+} = +1.0v, v_{V} = 0v, v_{CM}$	$= v_{OUT} = v_{V_+}/2, n_L = n_{V_+}, n_L$	$f = 250$, build values indicate $-400 \le 1$	$j \leq +05$ O, unless noted

Symbol	Parameter	Condition	Min	Тур	Max	Units
V _{OS}	Input Offset Voltage			0.9	7 9	mV mV
TCV _{OS}	Input Offset Voltage Temperature Drift			2.0		μV/°C
I _B	Input Bias Current			1	10 500	pA pA
I _{OS}	Input Offset Current			0.01	0.5 75	pA pA
R _{IN}	Input Resistance			>10		TΩ
+PSRR	Positive Power Supply Rejection Ratio	$1.8V \le V_{V_+} \le 5V, V_{V} = 0V, V_{CM} = V_{OUT} = 0.9V$	60	85		dB
–PSRR	Negative Power Supply Rejection Ratio	$ \begin{array}{l} -1.8V \leq V_{V-} \leq -5V, \ V_{V+} = 0V, \\ V_{CM} = V_{OUT} = -0.9V \end{array} $	60	85		dB
CMRR	Common-Mode Rejection Ratio	$V_{CM} = -0.2V$ to +2.0V	50	70		dB
C _{IN}	Common Mode Input Capacitance			3		pF
V _{OUT}	Output Voltage Swing	output high, $R_L = 100k$, specified as $V_{V+} - V_{OUT}$		0.14	1 1 1	mV mV
		output low, R _L = 100k		0.14	1 1	mV mV
		output high, $R_L = 2k$, specified as $V_{V+} - V_{OUT}$		6.8	23 34	mV mV
		output low, $R_L = 2k$		6.8	23 34	mV mV
I _{SC}	Output Short Circuit Current	sourcing, V _{OUT} = 0V	15	25		mA
	Note 6	sinking, V _{OUT} = 1.8V	15	25		mA
A _{VOL}	Voltage Gain	sourcing		400		V/mV
		sinking		400	35	V/mV
I _s	Supply Current	$V_{V+} = 1.8V, V_{OUT} = V_{V+}/2$		15	35	μΑ

AC Electrical Characteristics (1.8V)

 $V+=+1.8V, V-=0V, V_{CM}=V_{OUT}=V_{V+}/2; R_L=1M; T_J=25^{\circ}C, \text{ bold } \text{values indicate } -40^{\circ}C \leq T_J \leq +85^{\circ}C; \text{ unless noted } T_J \leq +85^{\circ}C; \text{ and } T_J \leq$

SR	Slew Rate	voltage follower, 1V step, $R_L = 100k@0.9V$ $V_{OUT} = 1V_{P-P}$	0.015	V/µs
GBW	Gain Bandwidth Product		25	kHz

DC Electrical Characteristics (2.7V)

 $V_{V+} = +2.7V, V_{V-} = 0V, V_{CM} = V_{OUT} = V_{V+}/2; R_L = 1M; T_J = 25^{\circ}C, \text{ bold } \text{values indicate } -40^{\circ}C \leq T_J \leq +85^{\circ}C; \text{ unless noted}$

Symbol	Parameter	Condition	Min	Тур	Max	Units
V _{OS}	Input Offset Voltage			0.9	7 9	mV mV
TCV _{OS}	Input Offset Voltage Temperature Drift			2.0		μV/°C
I _B	Input Bias Current			1	10 500	рА pA
I _{OS}	Input Offset Current			0.01	0.5 75	рА pA
R _{IN}	Input Resistance			>10		TΩ
+PSRR	Positive Power Supply Rejection Ratio	$2.7V \le V_{V_+} \le 5V, V_{V} = 0V, V_{CM} = V_{OUT} = 1.35V$	60	90		dB
–PSRR	Negative Power Supply Rejection Ratio	$-2.7V \le V_{V-} \le -5V, V_{V+} = 0V,$ $V_{CM} = V_{OUT} = -1.35V$	60	90		dB
CMRR	Common-Mode Rejection Ratio	$V_{CM} = -0.2V \text{ to } +2.9V$	52	75		dB
C _{IN}	Common Mode Input Capacitance			3		pF
V _{OUT}	Output Voltage Swing	output high, $R_L = 100k$, specified as $V_{V+} - V_{OUT}$		0.2	1 1	mV mV
		output low, R _L = 100k		0.2	1 1	mV mV
		output high, $R_L = 2k$, specified as $V_{V+} - V_{OUT}$		10	33 50	mV mV
		output low, $R_L = 2k$		10	33 50	mV mV
I _{SC}	Output Short Circuit Current	sourcing, V _{OUT} = 0V	30	50		mA
	Note 6	sinking, V _{OUT} = 2.7V	30	50		mA
A _{VOL}	Voltage Gain	sourcing		400		V/mV
		sinking		400	1 1 33 50 33 50	V/mV
l _s	Supply Current	$V_{V+} = 2.7V, V_{OUT} = V_{V+}/2$		17	42	μΑ

AC Electrical Characteristics (2.7V)

 $V_{+} = +2.7V, V_{-} = 0V, V_{CM} = V_{OUT} = V_{V_{+}}/2; R_{L} = 1M; T_{J} = 25^{\circ}C, \text{ bold } \text{values indicate } -40^{\circ}C \leq T_{J} \leq +85^{\circ}C; \text{ unless noted } = 10^{\circ}C \leq T_{J} \leq +85^{\circ}C; \text{ and } = 10^{\circ}C \leq +10^{\circ}C \leq +10^{\circ}C \leq +10^{\circ}C \leq +10^{\circ}C < +10^{$

Symbol	Parameter	Condition	Min	Тур	Мах	Units
SR	Slew Rate	voltage follower, 1V step, $R_L = 100k@1.35V$ $V_{OUT} = 1V_{P-P}$		0.015		V/µs
GBW	Gain Bandwidth Product			25		kHz

DC Electrical Characteristics (5V)

		= 25°C, bold values indicate $-40^{\circ}C \le T$. OF°C unloss noted
$V_{11} = +3.0V$, $V_{11} = 0V$, $V_{CM} = V_{CM}$	$\tau = V_{V_{1}}/2$, $\Pi_{1} = V $, $ _{1}$	$= 25$ C. DOID values indicate -40 C ≤ 1	$1 \leq +65$ C: unless noted
		,	

Symbol	Parameter	Condition	Min	Тур	Max	Units
V _{OS}	Input Offset Voltage			0.9	7 9	mV mV
TCV _{OS}	Input Offset Voltage Temperature Drift			2.0		μV/°C
I _B	Input Bias Current			1	10 500	pA pA
I _{OS}	Input Offset Current			0.01	0.5 75	рА pA
R _{IN}	Input Resistance			>10		TΩ
+PSRR	Positive Power Supply Rejection Ratio	$5V \le V_{V+} \le 10V, V_{V-} = 0V,$ $V_{CM} = V_{OUT} = 2.5V$	65	95		dB
–PSRR	Negative Power Supply Rejection Ratio	$-5V \le V_{V-} \le -10V, V_{V+} = 0V, V_{CM} = V_{OUT} = -2.5V$	65	95		dB
CMRR	Common-Mode Rejection Ratio	$V_{CM} = -0.2V$ to +5.2V	57	80		dB
C _{IN}	Common Mode Input Capacitance			3		pF
V _{OUT}	Output Voltage Swing	output high, $R_L = 100k$, specified as $V_{V+} - V_{OUT}$		0.3	1.5 1.5	mV mV
		output low, R _L = 100k		0.3	1.5 1.5	mV mV
		output high, $R_L = 2k$, specified as $V_{V+} - V_{OUT}$		15	50 75	mV mV
		output low, $R_L = 2k$		15	50 75	mV mV
I _{SC}	Output Short Circuit Current	sourcing, V _{OUT} = 0V	80	100		mA
	Note 6	sinking, V _{OUT} = 5V	80	100		mA
A _{VOL}	Voltage Gain	sourcing		500		V/mV
		sinking		500		V/mV
I _S	Supply Current	$V_{V+} = 5V, V_{OUT} = V_{V+}/2$		20	50	μA

AC Electrical Characteristics (5V)

 $V+=+5V, V-=0V, V_{CM}=V_{OUT}=V_{V+}/2; R_L=1M; T_J=25^{\circ}C, \text{ bold } \text{values indicate } -40^{\circ}C \leq T_J \leq +85^{\circ}C; \text{ unless noted } V_{V+}=1000 \text{ s}^{-1}, V_{CM}=1000 \text{ s}^{-1}, V_{CM}=10000 \text{ s}^{-1}, V_{CM}=1000 \text{ s}^{-1}, V_{CM}=10000 \text{ s}^{-1}, V_{CM}=100000 \text{ s}^{-1}, V_{CM}=100000 \text{ s}^{-1}, V_{CM}=1000000000000000000$

Symbol	Parameter	Condition	Min	Тур	Max	Units
SR	Slew Rate	voltage follower, 1V step, $R_L = 100k@1.5V$ $V_{OUT} = 1V_{P-P}$		0.02		V/µs
GBW	Gain Bandwidth Product			25		kHz

DC Electrical Characteristics (10V)

 $V_{V+} = +10V, V_{V-} = 0V, V_{CM} = V_{OUT} = V_{V+}/2; R_L = 1M; T_J = 25^{\circ}C, \text{ bold values indicate } -40^{\circ}C \le T_J \le +85^{\circ}C; \text{ unless noted } = 100^{\circ}C \le T_J \le +85^{\circ}C; \text{ and } = 100^{\circ}C \le T_J \le +100^{\circ}C \le +100^{\circ}$

Symbol	Parameter	Condition	Min	Тур	Max	Units
V _{OS}	Input Offset Voltage			0.9	7 9	mV mV
TCV _{OS}	Input Offset Voltage Temperature Drift			2.0		μV/°C

Symbol	Parameter	Condition	Min	Тур	Max	Units
I _B	Input Bias Current			1	10 500	pA pA
I _{OS}	Input Offset Current			0.01	0.5 75	pA pA
R _{IN}	Input Resistance			>10		TΩ
+PSRR	Positive Power Supply Rejection Ratio	$5V \le V_{V+} \le 10V, V_{V-} = 0V,$ $V_{CM} = V_{OUT} = 2.5V$	65	95		dB
-PSRR	Negative Power Supply Rejection Ratio	$ \begin{array}{l} -5V \leq V_{V-} \leq -10V, \ V_{V+} = 0V, \\ V_{CM} = V_{OUT} = -2.5V \end{array} $	65	95		dB
CMRR	Common-Mode Rejection Ratio	$V_{CM} = -0.2V \text{ to } +10.2V$	60	85		dB
C _{IN}	Common Mode Input Capacitance			3		pF
V _{OUT}	Output Voltage Swing	output high, $R_L = 100k$, specified as $V_{V+} - V_{OUT}$		0.45	2.5 2.5	mV mV
		output low, R _L = 100k		0.45	2.5 2.5	mV mV
		output high, $R_L = 2k$, specified as $V_{V+} - V_{OUT}$		24	80 120	mV mV
		output low, $R_L = 2k$		24	80 120	mV mV
I _{SC}	Output Short Circuit Current Note 6	sourcing, V _{OUT} = 0V	100	200		mA
		sinking, V _{OUT} = 10V	100	200		mA
A _{VOL}	Voltage Gain	sourcing		500		V/mV
		sinking		500		V/mV
I _S	Supply Current	$V_{V+} = 10V, V_{OUT} = V_{V+}/2$		25	65	μΑ

AC Electrical Characteristics (10V)

 $V+=+10V, V-=0V, V_{CM}=V_{OUT}=V_{V+}/2; R_{L}=1M; T_{J}=25^{\circ}C, \text{ bold } \text{values indicate } -40^{\circ}C \leq T_{J} \leq +85^{\circ}C; \text{ unless noted } V_{L}=100, V_{L}=100$

Symbol	Parameter	Condition	Min	Тур	Max	Units
SR	Slew Rate	voltage follower, 1V step, $R_L = 100k@1.35V$ $V_{OUT} = 1V_{P-P}$		0.02		V/µs
GBW	Gain Bandwidth Product			25		kHz
φ _M	Phase Margin			50		0
G _M	Gain Margin			15		dB
e _N	Input Referred Voltage Noise	$f = 1 kHz, V_{CM} = 1.0V$		110		nV/\sqrt{Hz}
i _N	Input Referred Current Noise	f = 1kHz		0.03		pA/√Hz

General Notes: Devices are ESD protected; however, handling precautions are recommended. All limits guaranteed by testing on statistical analysis.

Note 1: Absolute maximum ratings indicate limits beyond which damage to the component may occur. Electrical specifications do not apply when operating the device outside its recommended operating ratings.

Note 2: I/O Pin Voltage is any external voltage to which an input or output is referenced.

Note 3: The maximum allowable power dissipation is a function of the maximum junction temperature, $T_{J(max)}$; the junction-to-ambient thermal resistance, θ_{JA} ; and the ambient temperature, T_A . The maximum allowable power dissipation at any ambient temperature is calculated using: $P_D = (T_{J(max)} - T_A) \div \theta_{JA}$. Exceeding the maximum allowable power dissipation will result in excessive die temperature.

Note 4: Thermal resistance, θ_{JA} , applies to a part soldered on a printed-circuit board.

Note 5: Human body model, 1.5k in series with 100pF.

Note 6: Short circuit may cause the device to exceed maxium allowable power dissipation. See Note 3.

Application Information

Input Common-Mode Voltage

The MIC7111 tolerates input overdrive by at least 300mV beyond either rail without producing phase inversion.

If the absolute maximum input voltage is exceeded, the input current should be limited to ± 5 mA maximum to prevent reducing reliability. A $10k\Omega$ series input resistor, used as a current limiter, will protect the input structure from voltages as large as 50V above the supply or below ground. See Figure 1.

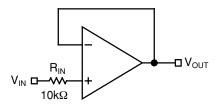


Figure 1. Input Current-Limit Protection

Output Voltage Swing

Sink and source output resistances of the MIC7111 are equal. Maximum output voltage swing is determined by the load and the approximate output resistance. The output resistance is:

$$R_{OUT} = \frac{V_{DROP}}{I_{LOAD}}$$

 V_{DROP} is the voltage dropped within the amplifier output stage. V_{DROP} and I_{LOAD} can be determined from the V_O (output swing) portion of the appropriate Electrical Characteristics table. I_{LOAD} is equal to the typical output high voltage minus V+/2 and divided by R_{LOAD} . For example, using the Electrical Characteristics DC (5V) table, the typical output voltage drop using a $2k\Omega$ load (connected to V+/2) is 0.015V, which produces an I_{LOAD} of:

$$\frac{2.5V - 0.015V}{2k\Omega} = 1.243mA$$

then:

F

$$R_{OUT} = \frac{15mV}{1.243mA} = 12.1 \approx 12\Omega$$

Driving Capacitive Loads

Driving a capacitive load introduces phase-lag into the output signal, and this in turn reduces op-amp system phase margin. The application that is least forgiving of reduced phase margin is a unity gain amplifier. The MIC7111 can typically drive a 500pF capacitive load connected directly to the output when configured as a unity-gain amplifier.

Using Large-Value Feedback Resistors

A large-value feedback resistor (> $500k\Omega$) can reduce the phase margin of a system. This occurs when the feedback resistor acts in conjunction with input capacitance to create phase lag in the fedback signal. Input capacitance is usually a combination of input circuit components and other parasitic capacitance, such as amplifier input capacitance and stray printed circuit board capacitance.

Figure 2 illustrates a method of compensating phase lag caused by using a large-value feedback resistor. Feedback capacitor C_{FB} introduces sufficient phase lead to overcome the phase lag caused by feedback resistor R_{FB} and input capacitance C_{IN}. The value of C_{FB} is determined by first estimating C_{IN} and then applying the following formula:

$$\mathsf{R}_{\mathsf{IN}} \times \mathsf{C}_{\mathsf{IN}} \leq \mathsf{R}_{\mathsf{FB}} \times \mathsf{C}_{\mathsf{FB}}$$

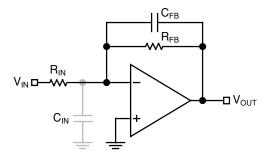


Figure 2. Cancelling Feedback Phase Lag

Since a significant percentage of C_{IN} may be caused by board layout, it is important to note that the correct value of C_{FB} may

change when changing from a breadboard to the final circuit layout.

Typical Circuits

Some single-supply, rail-to-rail applications for which the MIC7111 is well suited are shown in the circuit diagrams of Figures 3 through 7.

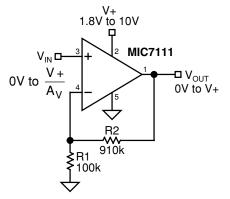


Figure 3a. Noninverting Amplifier

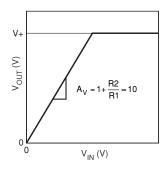


Figure 3b. Noninverting Amplifier Behavior

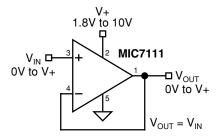


Figure 4. Voltage Follower/Buffer

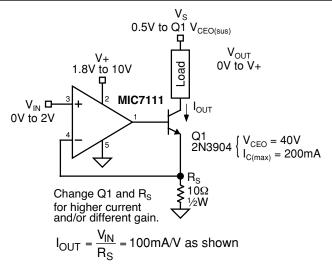


Figure 5. Voltage-Controlled Current Sink

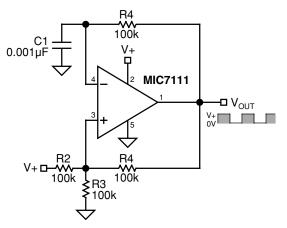


Figure 6. Square Wave Oscillator

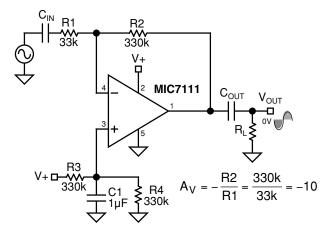
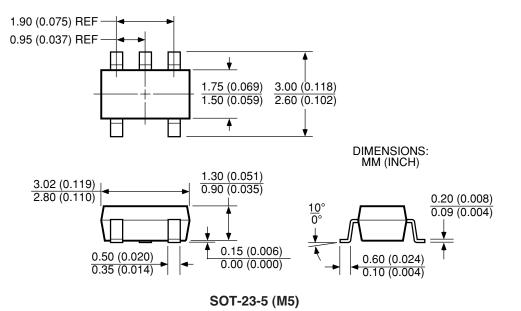


Figure 7. AC-Coupled Inverting Amplifier

Package Information



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